ECTLCCBxxVB

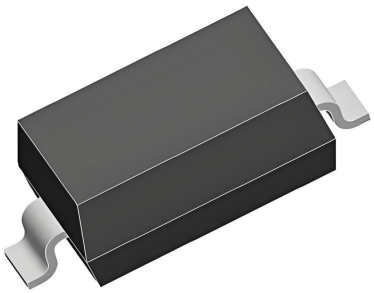
Bidirectional Ultra Low Capacitance TVS ARRAY

The ECTLCCBxxVB is ultra low capacitance transient voltage suppressor arrays, designed to protect applications such as portable electronics and SMART phones. This series is available in both unidirectional and bidirectional configurations and is rated at 350 Watts for an 8/20μs waveform.

The ECTLCCBxxVB meets IEC 61000-4-2 (ESD) and IEC 61000-4-4 (EFT) requirements. At higher operating frequencies or faster edge rates, insertion loss and signal integrity are a major concern. This series offers an ultra low capacitance and low leakage current in a miniature SOD-323 package.

Features

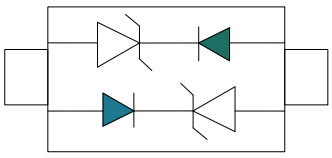
- 350 Watts Peak Pulse Power per Line (8 x 20 us Waveform)
- Replacement for MLV (0805)
- Protects One Power or I/O Port
- Low Clamping Voltage
- Available in Multiple Voltages:3.3V,5.0V,8.0V,12V,15V,24V
- Ultra Low Capacitance: 0.8pF (Typical)
- Response Time is < 1 ns
- Meets MSL 1 Requirements
- Solid-state silicon avalanche technology
- ROHS compliant



SOD-323

Main applications

- Hand−Held Portable Applications
- Networking and Telecom(Ethernet 10/100/1000 Base T)
- USB Interface
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers



Protection solution to meet

- IEC61000-4-2 (ESD) ±30kV (air), ±30kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)

Ordering Information

Device	Qty per Reel	Reel Size
ECTLCCBxxVB	3000	7 Inch

"xx" =Working Peak Reverse Voltage

Maximum ratings (Tamb=25℃ Unless Otherwise Specified)			
Parameter	**Symbol**	**Value**	**Unit**
Peak Pulse Power (tp=8/20μs waveform)	P_{PPP}	350	Watts
ESD Rating per IEC61000-4-2： Contact Air		30 30	KV
Lead Soldering Temperature	T_L	260 (10 sec.)	℃
Operating Temperature Range	T_J	-55 ~ 150	℃
Storage Temperature Range	T_{STG}	-55 ~ 150	℃
Lead Solder Temperature − Maximum (10 Second Duration)	T_L	260	℃

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

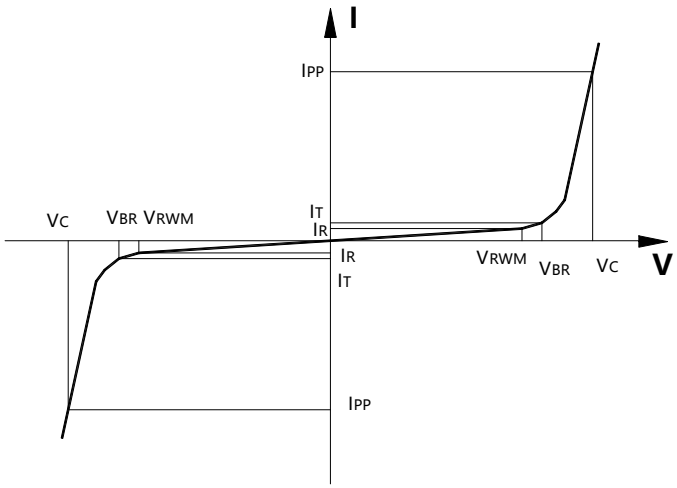
**Other voltages may be available upon request.*

1. Non-repetitive current pulse, per Figure 1.

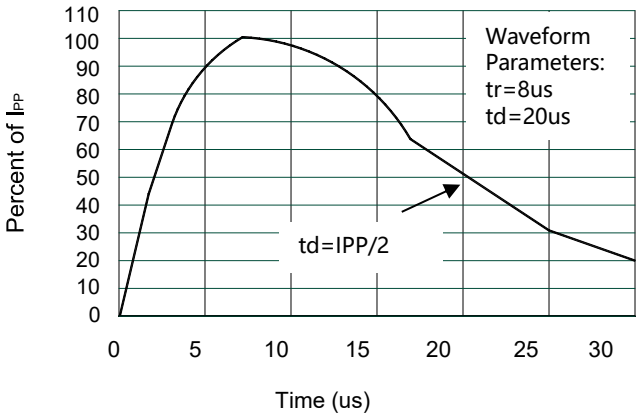
Device	V_{RWM}	I_R @ V_{RWM}	V_{BR} @ 1 mA	V_{C1}	Ipp@8/20us	Capacitance		P_{PK}
			(Volts)	@ 1 A	(Amps)	@ V_R = 0 V, 1 MHz (pF)		
	(V)	(uA)	Min	(V)	Max.	Typ	Max.	(W)
ECTLCCB3V3B	3.3	5	4	7.5	20	0.8	1.5	350
ECTLCCB5VB	5	1	6	9.8	17	0.8	1.5	350
ECTLCCB8VB	8	1	8.5	13.6	15	0.8	1.5	350
ECTLCCB12VB	12	1	13.3	17.8	11	0.8	1.5	350
ECTLCCB15VB	15	1	16.7	23.5	10	0.8	1.5	350
ECTLCCB24VB	24	1	26.7	38	6	0.8	1.5	350

Junction capacitance is measured in VR=0V,F=1MHz

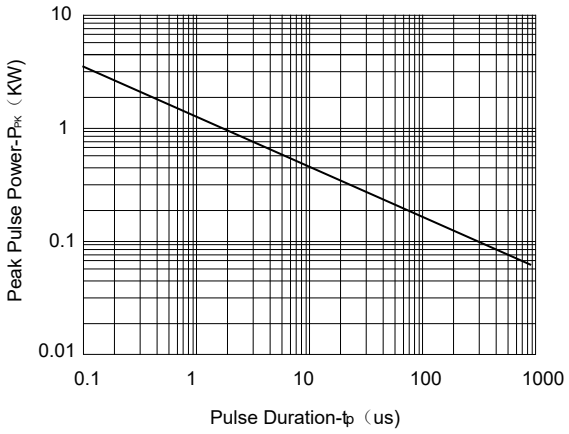
Symbol	Parameter
V_{RWM}	Working Peak Reverse Voltage
V_{BR}	Breakdown Voltage @ I_T
V_C	Clamping Voltage @ I_{PP}
I_T	Test Current
I_{RM}	Leakage current at V_{RWM}
I_{PP}	Peak pulse current
C_O	Off-state Capacitance
C_J	Junction Capacitance



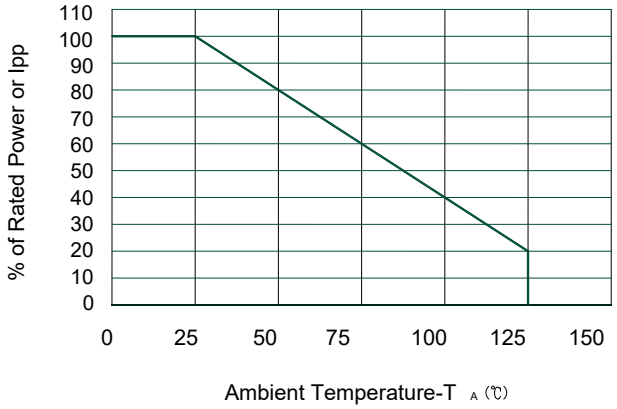
Typical electrical characterist applications



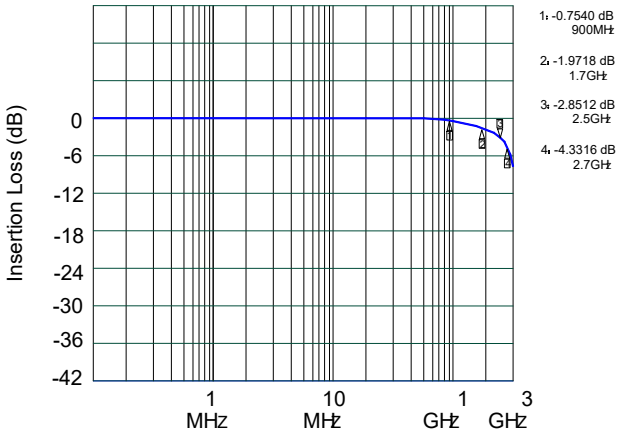
Pulse Waveform



Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve



Insertion Loss S21

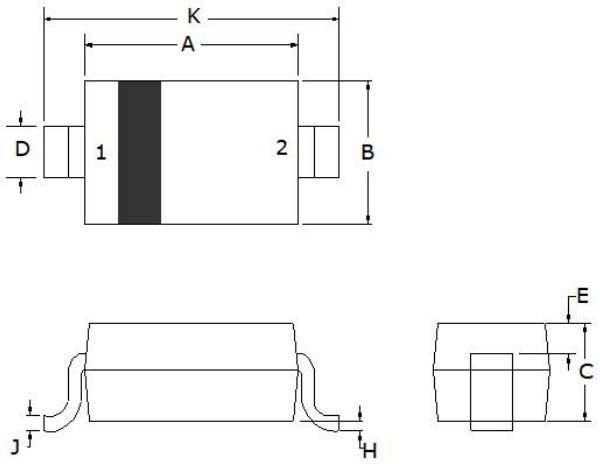
Package Information

SOD-323

Mechanical Data

Case: SOD-323

Case Material: Molded Plastic. UL Flammability



Dim	Millimeters	
	Min	Max
A	1.60	1.80
B	1.2	1.40
C	0.80	0.90
D	0.25	0.35
E	0.15REF	
H	0	0.10
J	0.08	0.15
K	2.50	2.70

Recommended Pad outline